

DESCRIPTION

INKA214AP1 is a Silicon N-channel Active Clamp MOSFET. The built in clamp diode connected between drain and gate protects the MOS-FET from the counter electromotive force in switching drive of the inductance load.

FEATURE

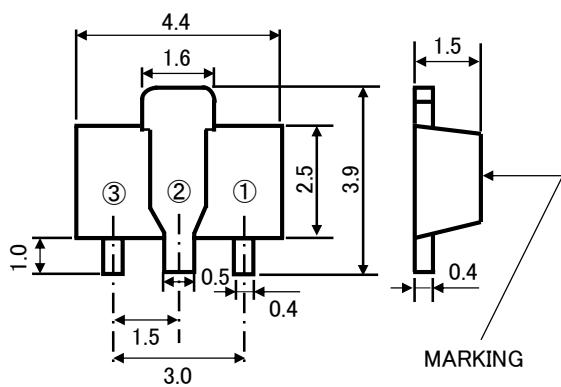
- The built in clamp diode connected between drain and gate.
- Built in bias resistor enables reduction of parts count.
- Drive voltage 4V

APPLICATION

Motor, Solenoid drive etc

OUTLINE DRAWING

Unit:mm



TERMINAL CONNECTER

①:GATE
②:DRAIN
③:SOURCE

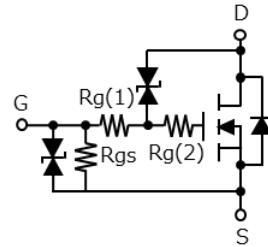
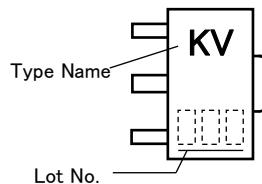
JEITA:SC-62
JEDEC:SOT-89

MAXIMUM RATINGS (Ta=25°C)

Symbol	Parameter	Rating	Unit
VGSS	Gate-Source Voltage	10	V
ID	Drain Current(DC)	2(※1)	A
IDP	Drain Current(Pulse)	6(※2)	A
PD	Total Power Dissipation	0.75(※1)	W
Tch	Channel Temperature	+150	°C
Tstg	Storage temperature	-55~+150	°C

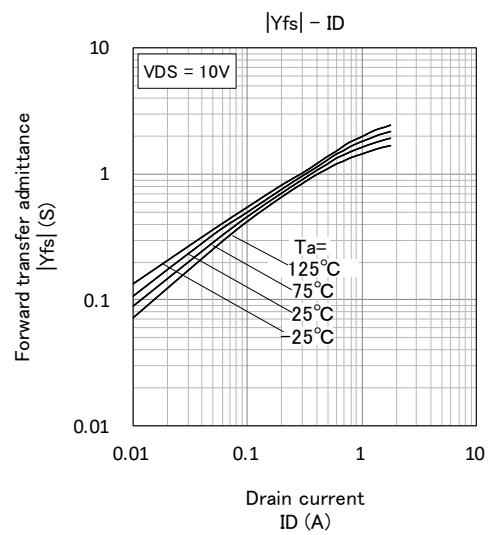
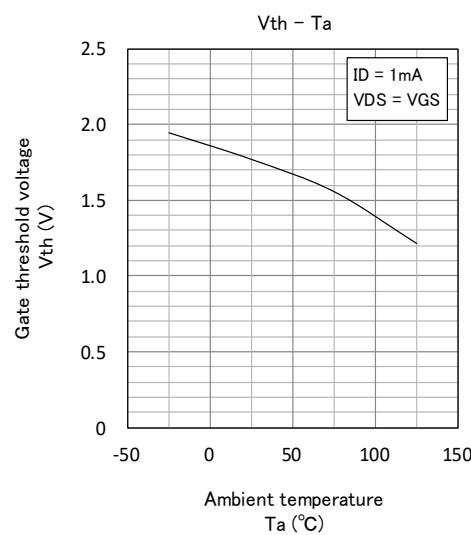
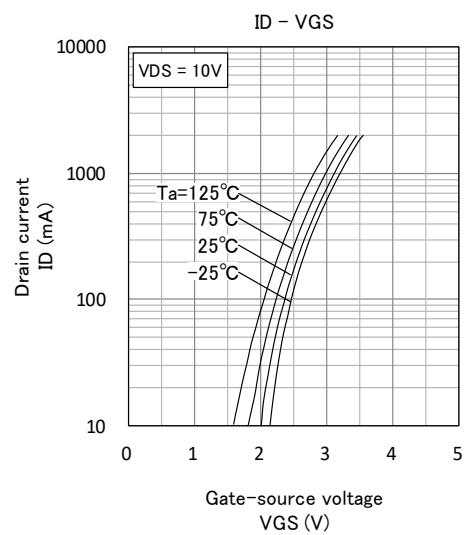
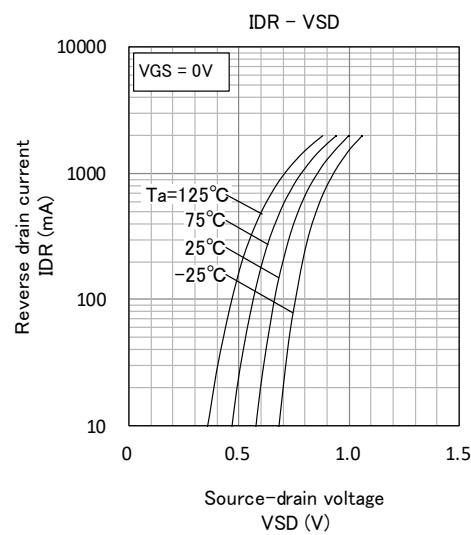
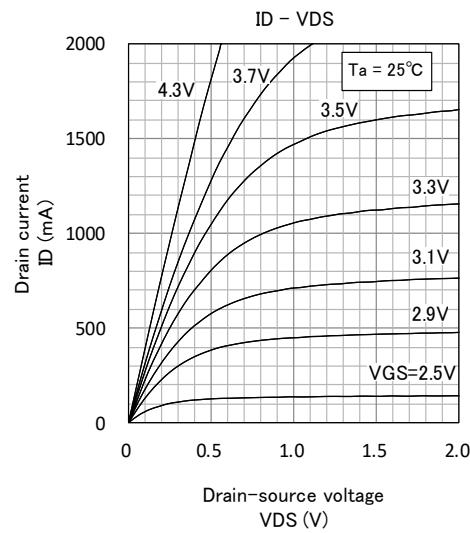
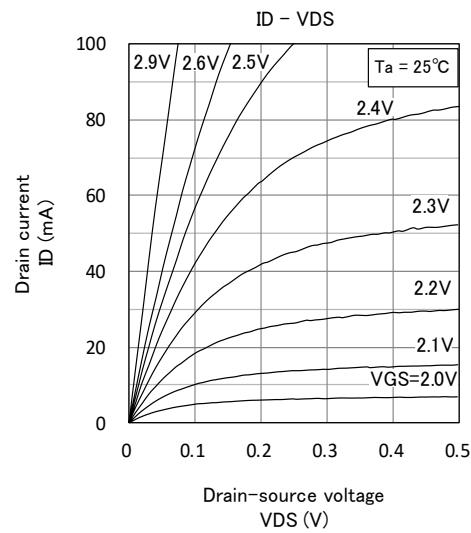
※1 package mounted on 19mm × 45mm × 1mm glass-epoxy substrate

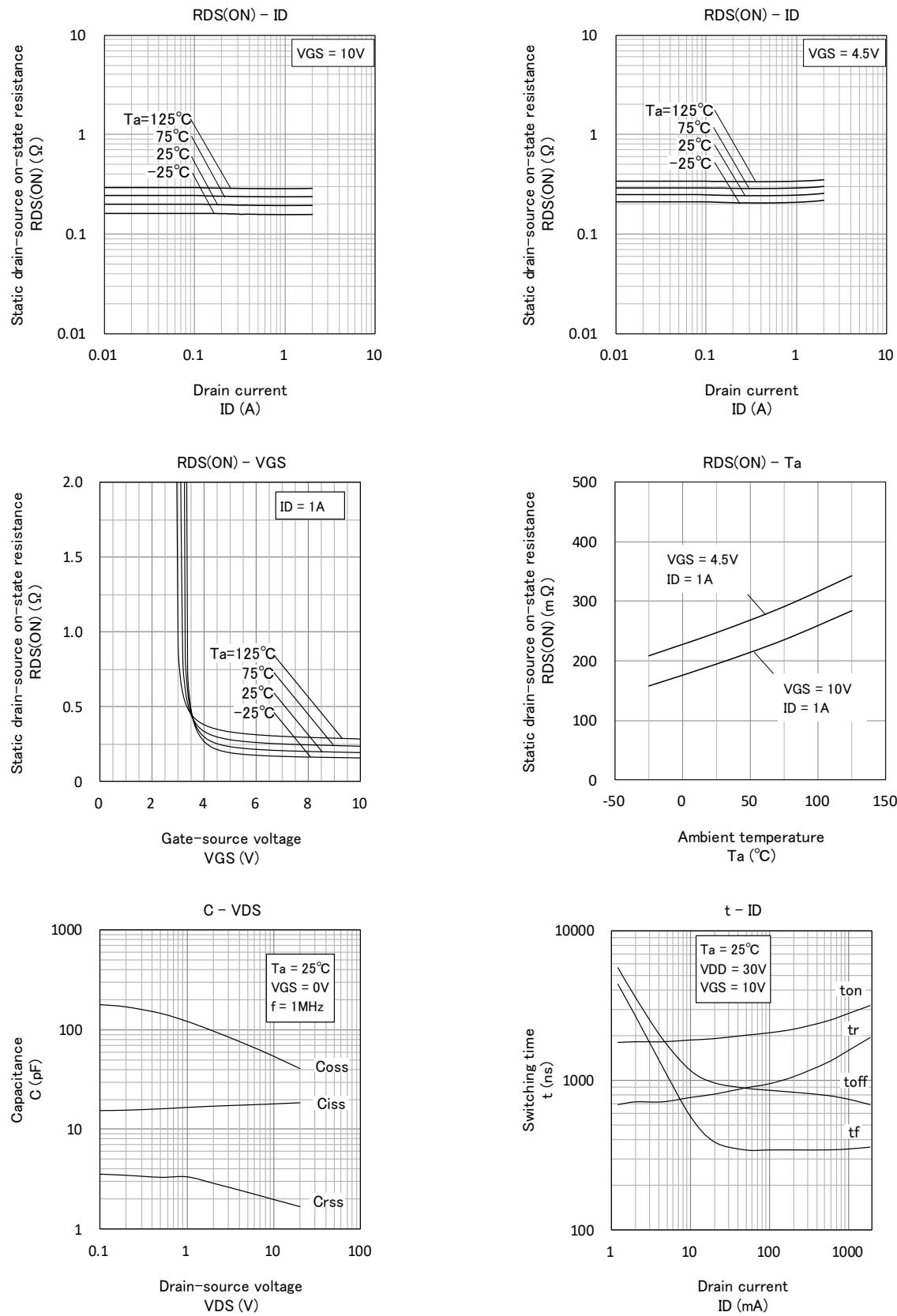
※2 Pw≤1ms, Duty cycle≤1%

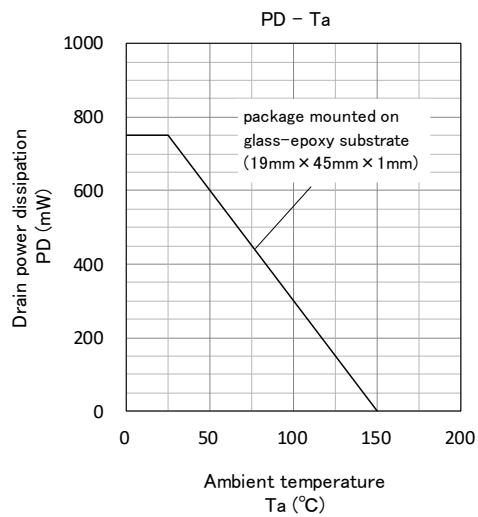
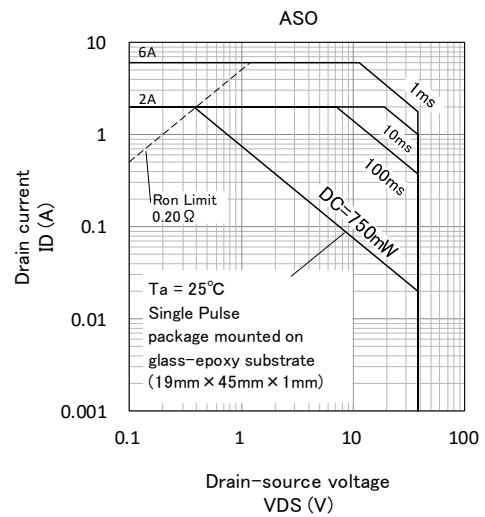
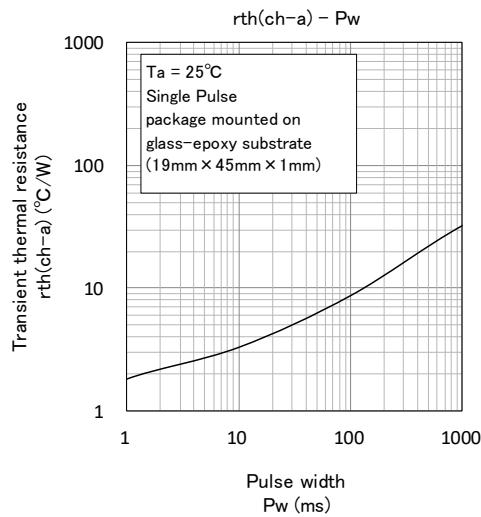
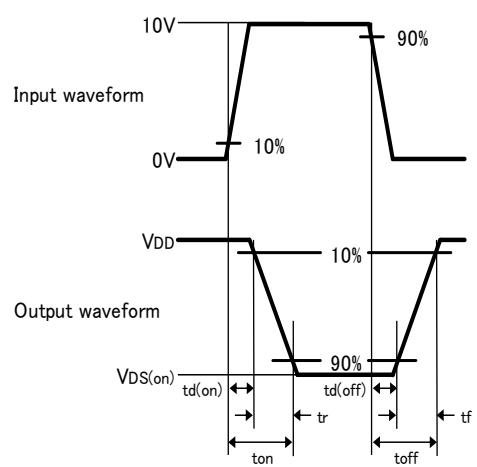
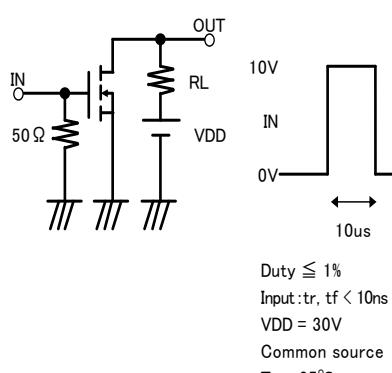
EQUIVALENT CIRCUIT**MARKING****ELECTRICAL CHARACTERISTICS (Ta=25°C)**

Parameter	Symbol	Test Condition	Limit			Unit
			MIN	TYP	MAX	
Drain-Source Breakdown Voltage	V _{(BR)DSS}	I _D =10mA, V _{GS} =0V	38	—	62	V
Gate-Source Leak current	I _{GSS}	V _{GS} =±5V, V _{DS} =0V	—	—	±100	μA
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =30V, V _{GS} =0V	—	—	1.0	μA
Gate Threshold Voltage	V _{th}	I _D =1mA, V _{DS} =V _{GS}	1.0	—	2.5	V
Forward Transfer Admittance	Y _{fs}	V _{DS} =10V, I _D =1A	—	2	—	S
Static Drain-Source On-State Resistance	R _{DS(ON)}	I _D =1A, V _{GS} =10V	—	150	—	mΩ
		I _D =1A, V _{GS} =4.5V	—	200	—	mΩ
Gate-Source Resistance	R _{gs}		—	100	—	kΩ
Gate Resistance1	R _{g(1)}		—	1.5	—	kΩ
Gate Resistance2	R _{g(2)}		—	500	—	Ω
Input Capacitance	C _{iss}	V _{DS} =10V, V _{GS} =0V, f=1MHz	—	20	—	pF
Output Capacitance	C _{oss}		—	55	—	pF
Switching Time	t _{on}	V _{DD} =30V, I _D =1A V _{GS} =0~10V	—	2.8	—	μs
	t _{off}		—	0.8	—	μs

TYPICAL CHARACTERISTICS





Switching time test condition

Keep safety first in your circuit designs!

·ISAHAYA Electronics Corporation puts the maximum effort into making semiconductor products better and more reliable, but there is always the possibility that trouble may occur with them. Trouble with semiconductors may lead to personal injury, fire or property damage. Remember to give due consideration to safety when making your circuit designs, with appropriate measures such as (1) placement of substitutive, auxiliary, (2) use of non-farmable material or (3) prevention against any malfunction or mishap.

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